Itinerant antiferromagnetism in BaCr₂As₂: Experimental characterization and electronic structure calculations

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We report single-crystal synthesis, specific-heat and resistivity measurements and electronic structure calculations for BaCr₂As₂. This material is a metal with itinerant antiferromagnetism, similar to the parent phases of Fe-based high-temperature superconductors, but differs in magnetic order. Comparison of bare bandstructure density of states and the low-temperature specific heat implies a mass renormalization of ~ 2 . BaCr₂As₂ shows stronger transition-metal–pnictogen covalency than the Fe compounds, and in this respect is more similar to BaMn₂As₂. This provides an explanation for the observation that Ni and Co doping is effective in the Fe-based superconductors, but Cr or Mn doping is not.

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I. INTRODUCTION

The discovery of high-temperature Fe-based superconductivity¹ has resulted in substantial activity leading to the finding of a wide range of Fe-based superconductors, including a number of materials in the ThCr₂Si₂ structure, prototype BaFe₂As₂.² Similar to the oxy-arsenides, BaFe₂As₂ is metallic and shows spin-density wave (SDW) antiferromagnetism when cooled.³ BaFe₂As₂ becomes superconducting when the SDW is destroyed, either by doping with holes² or electrons,⁴ or by using pressure.⁵ In fact, it is remarkable that superconductivity can be induced by doping on the Fesite using Co and Ni as electron dopants.^{4,6} This is in contrast to the behavior observed in cuprate superconductors, where alloving on the Cu site strongly suppresses superconductivity.

The electronic structure of BaFe₂As₂ is similar to the other iron based superconducting materials in that the Fermi energy (E_F) lies in at the bottom of a pseudogap in the electronic density of states. The corresponding Fermi surface then consists of small disconnected hole and electron pockets around the zone center and zone corner.⁷⁻¹⁰ Importantly the bands within 2 eV of the Fermi energy arise from Fe d states with only modest As p hybridization. BaCo₂As₂ and BaNi₂As₂ show very different properties, namely, those of a material very close to ferromagnetism,¹¹ and a low-temperature electron-phonon superconductor, respectively.¹²⁻¹⁴ Importantly, however, the electronic structures of BaT_2As_2 , T=Fe,Co,Ni, are closely related, with Fe d bands near E_F , modest hybridization with As, and a similar shaped density of states with a pseudogap at an electron count of six d electrons. The main differences in physical properties are due to the different electron counts of Fe^{2+} , Co²⁺, and Ni²⁺. This common behavior is also thought to be important for the superconductivity in the Co-doped superconductor BaFe2-xCoxAs2, whose electronic structure behaves as a coherent alloy.⁴ On the other hand, to our knowledge, superconductivity has not been reported in BaFe₂As₂ doped with Mn or Cr so far. BaMn₂As₂ shows an electronic structure very different from the *T*=Fe,Co,Ni compounds. In particular, it has strong spin-dependent hybridization between Mn *d* states and As *p* states, and is a small band-gap semiconductor with high exchange couplings and ordering temperature that result from the strong hybridization.^{15,16} Here we report investigation of the *T*=Cr material, BaCr₂As₂. This material is known to form in the ThCr₂Si₂ structure,¹⁷ but little has been reported about its physical properties. We find that similar to BaMn₂As₂ it has strong spin-dependent Cr *d*-As *p* hybridization, but unlike that material it is a renormalized antiferromagnetic metal, with a *G*-type (checkerboard) order and very strong magnetic interactions.

II. METHODS

BaCr₂As₂ single crystals were prepared starting from high-purity elements (>99.9%, source Alfa Aesar). The crystals were grown out of CrAs binary. Cr powder and As pieces were reacted slowly by heating to 300 °C (50 °C/hr, dwell 10 h), to 600 °C (30 °C/hr dwell 30 h), then to 900 °C $(30 \circ C/hr, dwell 24 h)$. A ratio of Ba: CrAs=1:4 was heated for 13 h at 1230 °C under partial argon atmosphere. The ampule was cooled at the rate of 2 °C/hr, followed by decanting of flux at 1120 °C. Electron probe microanalysis of a cleaved surface of the single crystal was performed on a JEOL JSM-840 scanning electron microscope using an accelerating voltage of 15 kV and a current of 20 nA with an EDAX brand energy-dispersive x-ray spectroscopy (EDS) device. EDS analyses on the crystal indicated a Ba:Cr:As ratio of 1:2:2, within the error bars. The phase purity of the crystals was determined using a Scintag XDS 2000 2Θ - 2Θ diffractometer (Cu K_{α} radiation). BaCr₂As₂ crystallizes with the ThCr₂Si₂ structure at room temperature (tetragonal space group I4/mmm, No. 139, Z=2). Lattice constants were determined from LeBail refinements using the program FULLPROF.¹⁸ The resulting room-temperature lattice parameters were a=3.9678(4) Å, c=13.632(3) Å.

Temperature-dependent electrical resistivity measurements were performed on a Quantum Design Physical Property Measurement System (PPMS). The electrical contacts were placed on the samples in the standard four-probe geometry, using Pt wires and silver paste. The resistivity was measured in the *ab* plane, i.e., $\rho_{ab}(T)$. Specific heat data, $C_p(T)$, were also obtained using the PPMS. The relaxation method was used from 2 to 200 K.

The first-principles calculations were done within the local-density approximation (LDA) using the general potential linearized augmented plane-wave (LAPW) method,19 similar to prior calculations for BaFe₂As₂.⁷ We used the reported experimental lattice parameters from literature,¹⁷ a =3.963 Å, c=13.600 Å, which are very close to the roomtemperature values determined here. The internal parameter, z_{As} was determined by energy minimization. The resulting value for the lowest energy G-type antiferromagnetic ordering is z_{As} =0.3572. This value shows sensitivity to magnetic order as in the Fe-based compounds.²⁰ A relaxation for ferromagnetic order yielded $z_{As}=0.3526$. We used wellconverged basis sets, including local orbitals to treat the semicore states and relax the Cr d state linearization.²¹ Relativistic effects were included at the scalar relativistic level. The LAPW sphere radii were $2.2a_0$ for Ba and $2.1a_0$ for Cr and As.

III. DENSITY-FUNCTIONAL CALCULATIONS

We begin with a discussion of the magnetic order. We calculated the energy as a function of magnetic ordering for different likely configurations. These were a non-spinpolarized calculation (i.e., no magnetism), and three magnetic orderings of the Fe planes, with both ferromagnetic and antiferromagnetic layer stackings for each. These orders were ferromagnetic, checkerboard nearest-neighbor antiferromagnetism, and a magnetic structure consisting of ferromagnetic chains of nearest-neighbor Fe, alternating antiferromagnetically, as in the SDW state of the undoped Fe superconducting materials. The results are summarized in Table I. As may be seen, checkerboard order with antiferromagnetic stacking, i.e., G-type antiferromagnetism, yields the lowest energy. This state has a Cr moment of $\sim 2\mu_{B}$. This is also the case if one uses $z_{As}=0.3526$, which is the value found for the ferromagnetic ordering. With this value the G-type antiferromagnetic ordering remains lower in energy and is in this case 0.155 eV below the ferromagnetic ordering on a per formula unit basis.

Turning to the details, one may note that the magnetic energy is large, $\sim -0.2 \text{ eV/Cr}$ for the ground state, and all the magnetic ordering patterns tested are lower energy than the non-spin-polarized case. However, the energy differences between different orderings are of almost the same scale as the magnetic energy of the ground state with respect to the non-spin-polarized case. For example, the difference between the chainlike order (S-A) that is the ground state of BaCr₂As₂ is 0.17 eV/Cr, i.e., $\sim 85\%$ of the magnetic energy in the ground state. This implies that the longitudinal degree of freedom will be important and therefore that the magnetic

TABLE I. LDA magnetic energy, E_{mag} , of BaCr₂As₂. The energies are given for z_{As} =0.3572, on a per formula unit basis (two Cr atoms) with respect to the non-spin-polarized energy. The moments, m_{Cr} , are the spin moments defined by the integral over the Cr LAPW sphere. The notation for the magnetic order is as follows: P denotes non-spin-polarized, otherwise the first letter denotes the in-plane magnetic order (F for ferromagnetic, C for checkerboard nearest-neighbor antiferromagnetism, and S for chains of like-spin Fe, as in the SDW of the Fe-based compounds), and the second denotes either antiferromagnetic stacking (A) or ferromagnetic stacking (F) along the *c* axis.

Magnetic order	$E_{\rm mag}~({\rm eV})$	$m_{\rm Cr}~(\mu_B)$
P	0.000	0.00
F-F	-0.157	1.56
F-A	-0.146	1.51
S-F	-0.059	1.73
S-A	-0.058	1.80
C-F	-0.382	2.05
C-A	-0.394	2.01

tism has significant itinerant character, in the sense that band structure (hopping) is important in the moment formation, as opposed to just atomic physics, with hopping important only in the intersite exchange. Also, one may note that the *c*-axis coupling is small compared to the in-plane coupling, and is antiferromagnetic for the ground state, but that the sign depends on the details of the in-plane order, implying that more than nearest-neighbor interactions are important. This is also apparent from the in-plane energetics. A simple fit of the energies for antiferromagnetic stacking to a Heisenberg model with nearest-neighbor (J_1) and next-nearest-neighbor (J_2) interactions, would yield antiferromagnetic J_1 and a large opposite (ferromagnetic) J_2 , $J_2/J_1 = -0.85$. The large magnitude of J_2 implies that this model is probably not reliable and that the interactions are probably long range, as might be expected in a metal with itinerant magnetism.

The main results for the LDA electronic structure are given in Figs. 1–3, which show the electronic density of states (DOS), the band structure, and the Fermi surface, respectively, for the G-type ground-state order. Figure 1 shows in addition the DOS for a ferromagnetic order. The compound is metallic for either order.

An examination of the DOS shows that the states near the E_F are hybridized Cr *d*-As *p* combinations and that the hybridization is spin dependent. This is similar to BaMn₂As₂, but rather different from the *T*=Fe,Co,Ni series where, as mentioned, the states near E_F are dominated by *d* character. In analyzing the DOS, it is important to keep in mind that the projections in the LAPW method are onto the LAPW spheres. Since a Cr 3*d* orbital is almost entirely contained within a 2.1*a*₀ sphere, the Cr *d* projection is a reasonable approximation to the Cr *d* contribution to the DOS. However, As *p* states are extended and would have substantial weight outside a sphere of this radius. Thus when considering the electronic structure, the difference between the total DOS and the Cr *d* projection is a better measure of the As *p* contribution than the As *p* projection, which would underes-



FIG. 1. (Color online) Calculated electronic density of states $BaCr_2As_2$ with ferromagnetic (top) and nearest-neighbor antiferromagnetic (bottom) ordering. Majority spin is shown above the axis and minority spin below. The projection is onto the LAPW sphere, radius 2.1 a_0 . In the top panel the Cr projections are for both atoms. In the bottom panel, spin up and spin down are identical, and the projections shown are majority and minority spin for one Cr atom. The total DOS is per formula unit.

timate the As contribution. Viewed in this way, As p orbitals contribute approximately 1/3 of the DOS at E_F and furthermore of the remaining 2/3, which is Cr d in character, the majority spin contributes more than twice as much as the minority spin. As may be seen comparing the top and bottom panels of Fig. 1, the details of this spin-dependent hybridization are sensitive to the magnetic order. This explains the large energy differences between different magnetic orders.



FIG. 2. Calculated band structure of $BaCr_2As_2$ with nearestneighbor antiferromagnetic ordering.



FIG. 3. (Color online) Calculated extended zone Fermi surface of antiferromagnetic $BaCr_2As_2$, showing a view off the *c* axis (left) and along the *c* axis (right). The shading is by velocity.

As mentioned, BaCr₂As₂ is metallic. We find a large multisheet Fermi surface. This consists of small rounded electron cubes around Γ , and two electron cylinders, also centered at Γ and running along the k_z direction. The outermost cylinder in particular has significant corrugation.

The density of states at the Fermi energy is moderately high, $N(E_F)=3.7 \text{ eV}^{-1}$ per formula unit, both spins basis. This corresponds to an nonrenormalized bare band specificheat coefficient $\gamma_0=9.3 \text{ mJ}/(\text{K}^2 \text{ mol})$. The calculated anisotropy is modest. The *ab*-plane and *c*-axis Fermi velocities are $\langle v_{xy}^2 \rangle^{1/2}=2.08 \times 10^5 \text{ m/s}$ and $\langle v_z^2 \rangle^{1/2}=1.08 \times 10^5 \text{ m/s}$, respectively. If the scattering rate is isotropic this would correspond to $\rho_c / \rho_{ab}=4$. If the scattering rate is the same for all Fermi surfaces, *c*-axis conduction will be roughly equally from the small Γ centered pocket and the outer electron cylinder, while the in-plane conduction will come mostly from two cylinders.

IV. TRANSPORT AND SPECIFIC HEAT

Figure 4 shows the temperature-dependent resistivity and specific heat for a single crystal of BaCr₂As₂. As mentioned, the resistivity was measured in the *ab* plane. As may be seen, the sample is clearly metallic with an increasing $\rho(T)$ and a finite $C_P(T)/T$ at low *T*. This is in accord with the results of our LDA calculations. There are no features suggesting a phase transition in either $\rho(T)$ or $C_P(T)$ from 2 to 200 K. This is perhaps not surprising considering the large energy



FIG. 4. Single-crystal specific heat and resistivity of $BaCr_2As_2$ as a function of temperature. The inset shows the linear dependence of C/T vs T^2 with finite value at T=0.

differences between different magnetic configurations found in the LDA calculations, as these differences would suggest an ordering temperature well above the maximum temperature of our measurements. We find specific-heat γ =19.3(1) mJ/(K² mol), i.e., ~9.6 mJ/(K² mol Cr). Comparing with the bare band-structure value, we find an enhancement of $\gamma/\gamma_0 \sim 2$. This is a substantial renormalization, comparable to the Fe-based superconductors, although the physics in BaCr₂As₂ may be different. The renormalization may come in part from the electron-phonon interaction and in part from spin-fluctuations or other correlation effects.

V. SUMMARY AND CONCLUSIONS

We find that $BaCr_2As_2$ is an itinerant antiferromagnetic metal with a complex multisheet Fermi surface and substantial (~2) specific-heat renormalization. While the electronic structure and magnetic order are different from those in the Fe-based superconducting materials, these results suggest

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that BaCr₂As₂ is an interesting material for further investigation. We also note that the stronger Cr-As covalency relative to the Fe-based superconductors means that Cr dopant atoms in those materials will produce more scattering than Co or Ni dopants, perhaps explaining why superconductivity has not yet been observed in Cr-doped BaFe₂As₂. Finally, we note that BaMn₂As₂ and BaMn₂Sb₂ have been discussed as potential thermoelectric materials.^{15,22} The present results showing similar bonding with As and spin-dependentmetal–As bonding in the Cr compound as was found previously in the Mn compounds suggest that Cr could be used for doping studies of the thermoelectric properties of the Mn phases.

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